



MCH6603

P-Channel Power MOSFET -50V, -0.14A, 23Ω, Dual MCPH6

ON Semiconductor®
<http://onsemi.com>

Features

- Low ON-resistance
- Ultrahigh-speed switching
- 1.5V drive
- Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		-50	V
Gate to Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-0.14	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-0.56	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)1unit	0.8	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling.

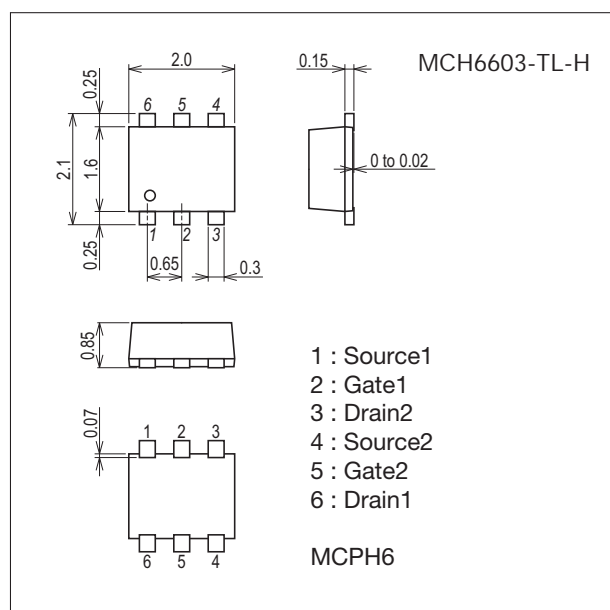
* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

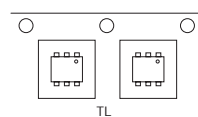
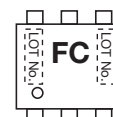
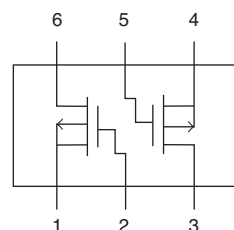
unit : mm (typ)

7022A-006



Product & Package Information

- Package : MCPH6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

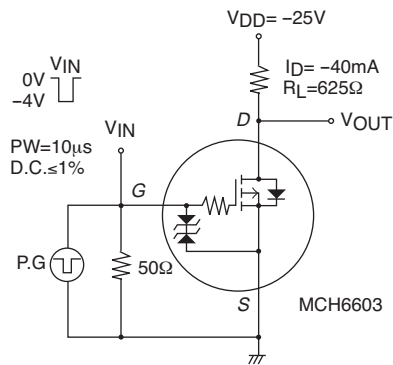
Packing Type : TL

Marking

Electrical Connection


MCH6603

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}, V_{GS} = 0\text{V}$	-50			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}$			-1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8\text{V}, V_{DS} = 0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}, I_D = -100\mu\text{A}$	-0.4		-1.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}, I_D = -40\text{mA}$	70	110		mS
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D = -40\text{mA}, V_{GS} = -4\text{V}$		18	23	Ω
	$R_{DS(on)2}$	$I_D = -20\text{mA}, V_{GS} = -2.5\text{V}$		20	28	Ω
	$R_{DS(on)3}$	$I_D = -5\text{mA}, V_{GS} = -1.5\text{V}$		30	60	Ω
Input Capacitance	C_{iss}	$V_{DS} = -10\text{V}, f = 1\text{MHz}$		7.4		pF
Output Capacitance	C_{oss}		4.2		pF	
Reverse Transfer Capacitance	C_{rss}		1.3		pF	
Turn-ON Delay Time	$t_d(on)$		20		ns	
Rise Time	t_r	See specified Test Circuit.		35		ns
Turn-OFF Delay Time	$t_d(off)$		160		ns	
Fall Time	t_f		150		ns	
Total Gate Charge	Q_g	$V_{DS} = -10\text{V}, V_{GS} = -10\text{V}, I_D = -70\text{mA}$		1.40		nC
Gate to Source Charge	Q_{gs}		0.16		nC	
Gate to Drain "Miller" Charge	Q_{gd}		0.23		nC	
Diode Forward Voltage	V_{SD}		$I_S = -70\text{mA}, V_{GS} = 0\text{V}$	-0.85	-1.2	V

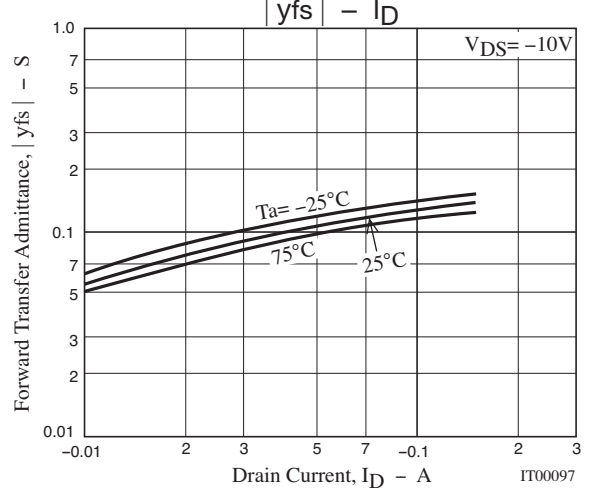
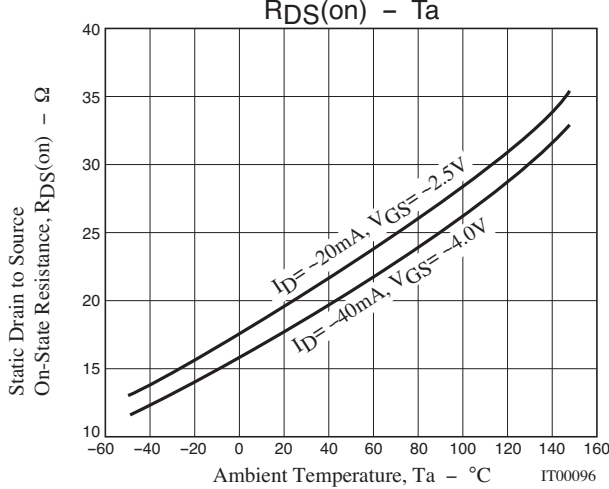
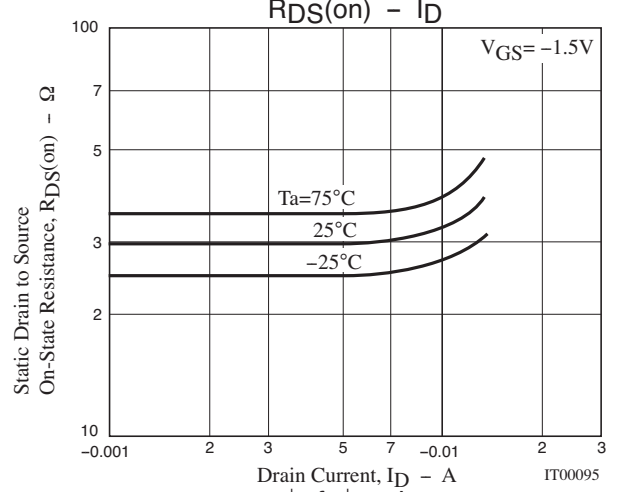
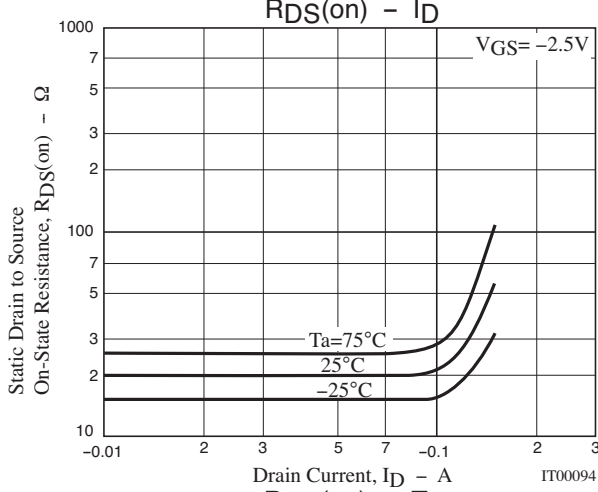
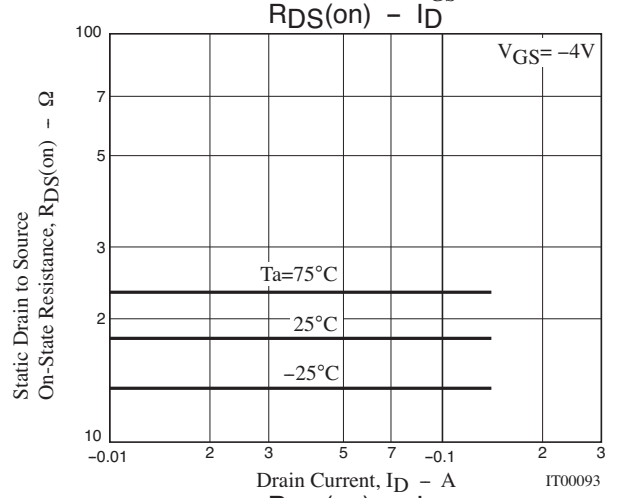
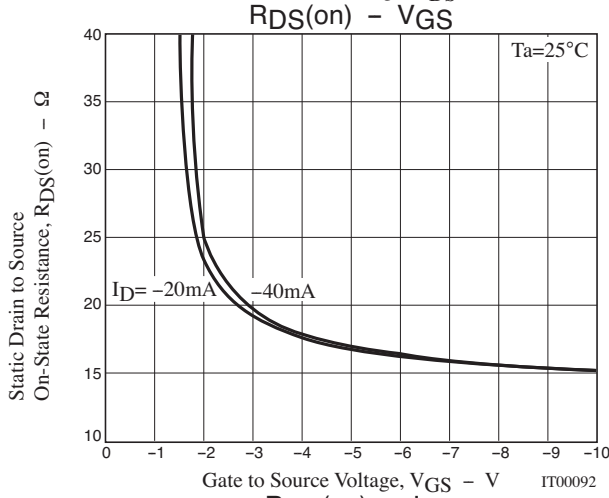
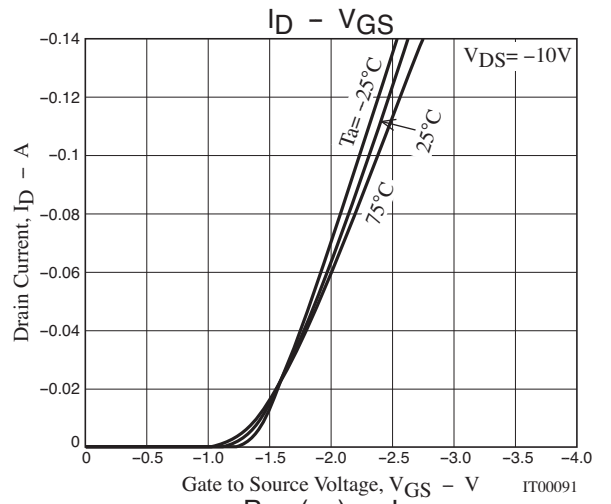
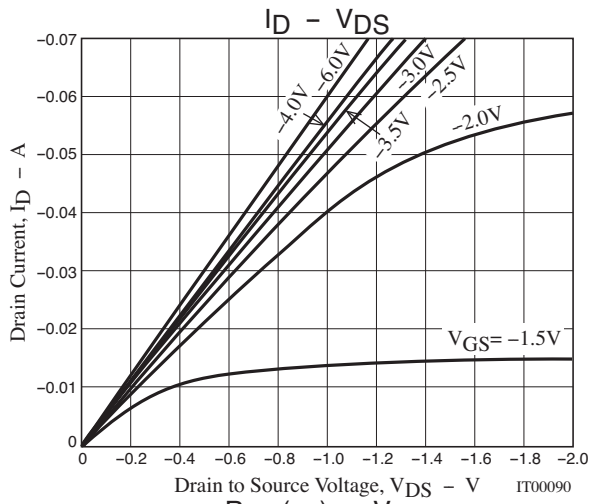
Switching Time Test Circuit



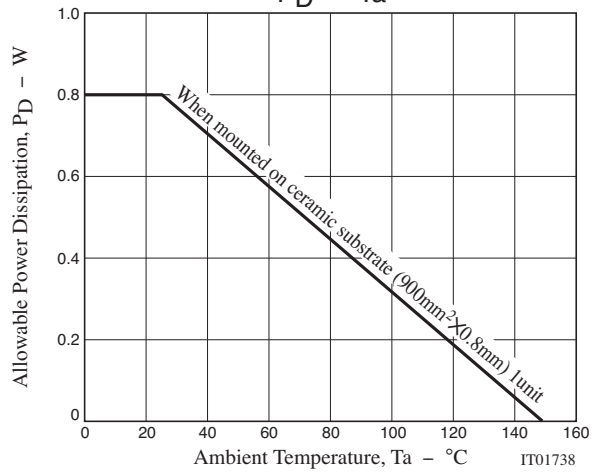
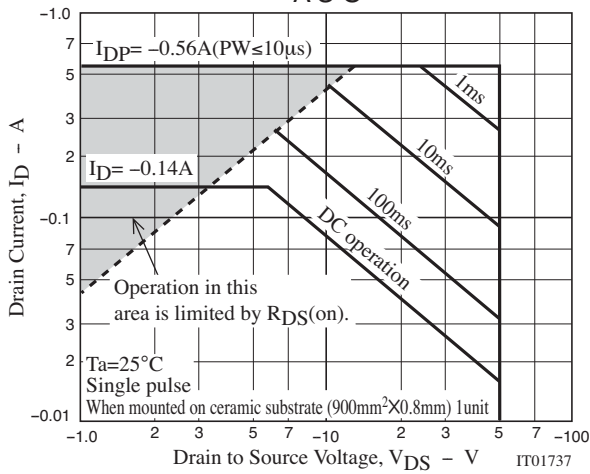
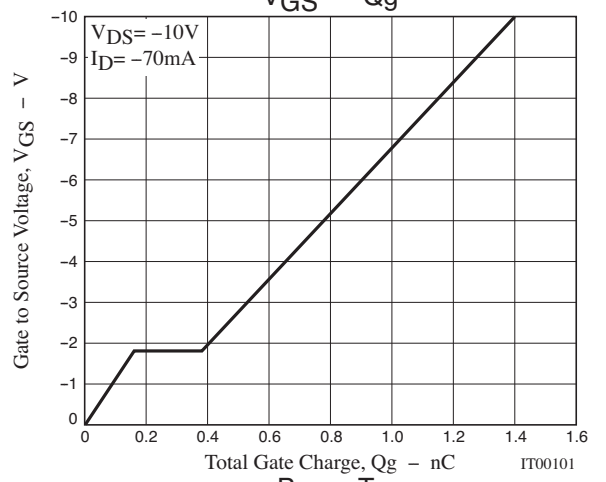
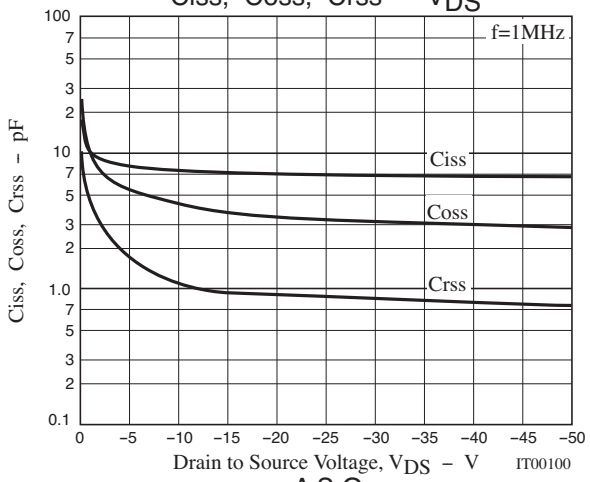
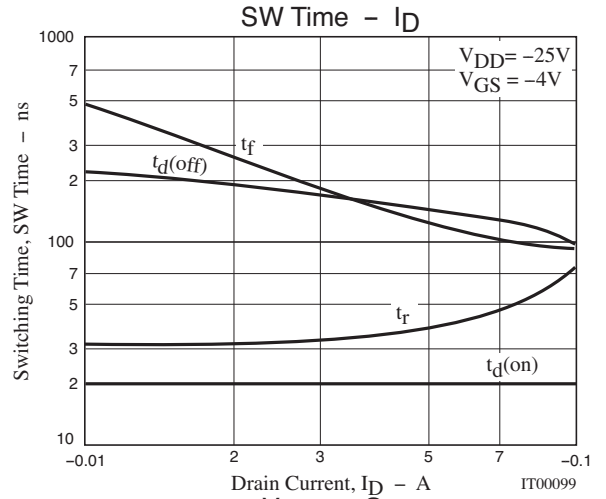
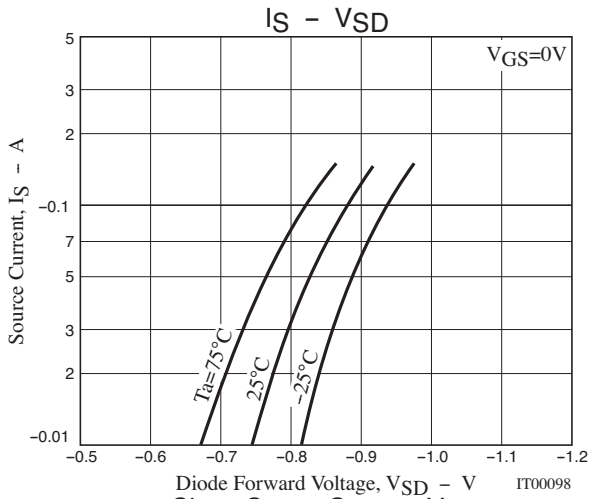
Ordering Information

Device	Package	Shipping	memo
MCH6603-TL-H	MCPH6	3,000pcs./reel	Pb-Free and Halogen Free

MCH6603

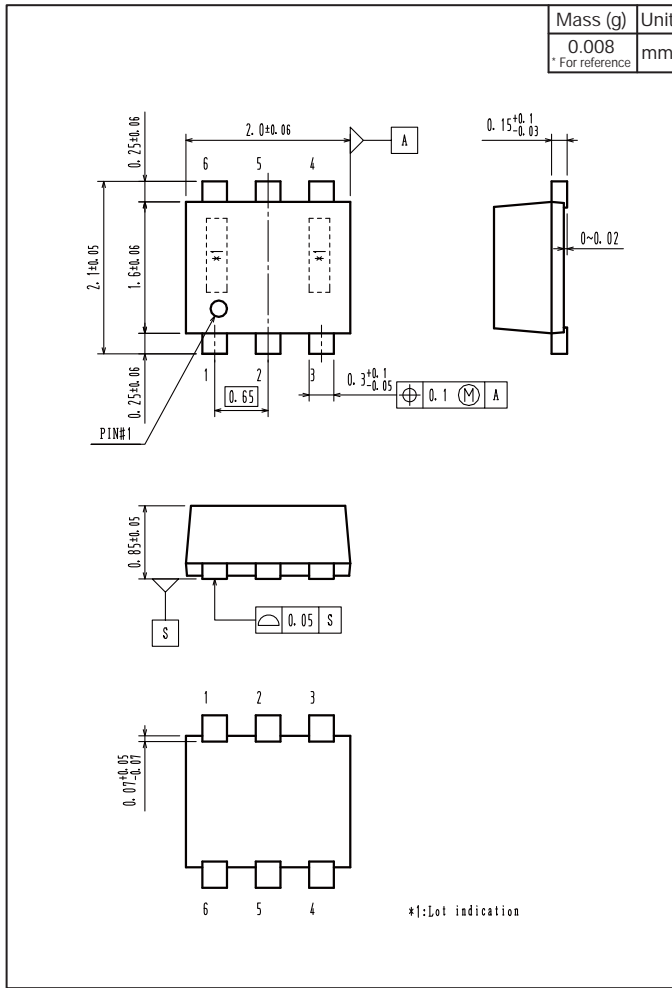


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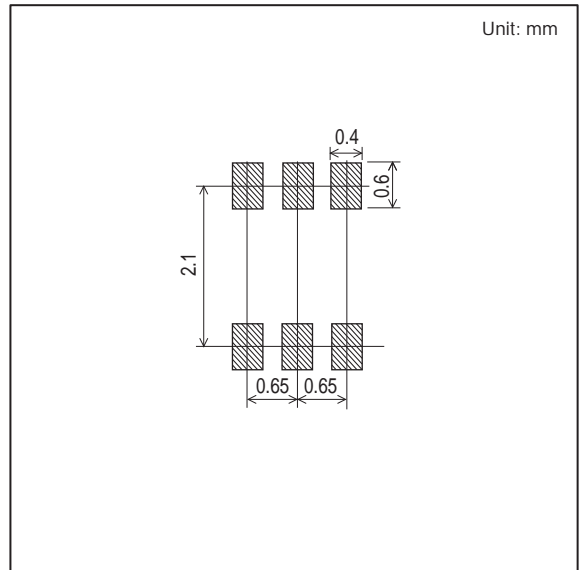


MCH6603

Outline Drawing MCH6603-TL-H



Land Pattern Example



Note on usage : Since the MCH6603 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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